PNP Epitaxial Planar Silicon Transistor



2SA1963

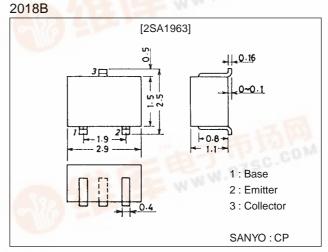
# High-Frequecy Low-Noise Amplifier, **Ultrahigh-Speed Switching Applications**

#### **Features**

· Low noise : NF=1.5dB typ (f=1GHz). · High gain :  $|S2le|^2 = 9dB$  typ (f=1GHz).  $\cdot$  High cutoff frequency :  $f_T$ =5GHz typ.

### **Package Dimensions**

unit:mm



### **Specifications**

#### Absolute Maximum Ratings at Ta = 25°C

3	The State of the S				
Parameter	Symbol	Conditions	Ratings	Unit	
Collector-to-Base Voltage	V <sub>CBO</sub>		-12	V	
Collector-to-Emitter Voltage	VCEO		-8	V	
Emitter-to-Base Voltage	V <sub>EBO</sub>		-2	V	
Collector Current	l <sub>C</sub>		-50	mA	
Collector Dissipation	PC	1	200	mW	
Junction Temperature	Tj		150	°C	
Storage Temperature	Tstg	A 7 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1	-55 to +150	°C	

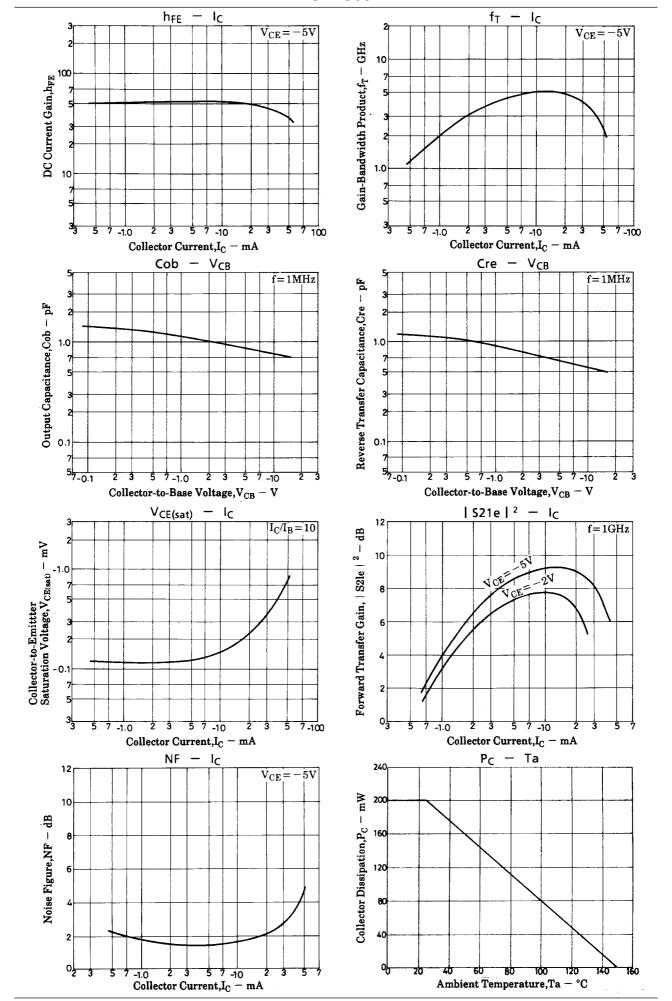
#### Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions		Unit		
Falameter	Symbol	Conditions	min	typ	max	Offic
Collector Cutoff Current	ICBO	V <sub>CB</sub> =-10V, I <sub>E</sub> =0			-1.0	μΑ
Emitter Cutoff Current	I <sub>EBO</sub>	V <sub>EB</sub> =-1V, I <sub>C</sub> =0			-1.0	μA
DC Current Gain	h <sub>FE</sub>	V <sub>CE</sub> =-5V, I <sub>C</sub> =-10mA	20*		120*	
Gain-Bandwidth Product	f <sub>T</sub>	V <sub>CE</sub> =-5V, I <sub>C</sub> =-10mA	3	5		GHz
Output Capacitance	C <sub>ob</sub>	V <sub>CB</sub> =-10V, f=1MHz		0.8	1.3	pF
Reverse Transfer Capacitance	C <sub>re</sub>	V <sub>CB</sub> =-10V, f=1MHz		0.55		pF
Forward Transfer Gain	S2le  2(1)	V <sub>CE</sub> =-5V, I <sub>C</sub> =-10mA, f=1GHz	7	9		dB
	S2le  2(2)	V <sub>CE</sub> =-2V, I <sub>C</sub> =-3mA, f=1GHz	W	6.5		dB
Noise Figure	NF	V <sub>CE</sub> =-5V, I <sub>C</sub> =-5mA, f=1GHz		1.5	3.0	dB

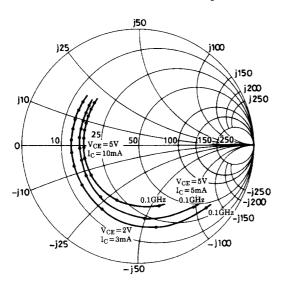
\*: The 2SA1963 is classified by 10mA h<sub>FE</sub> as follows: Marking: MS h<sub>FE</sub> ranks: 1, 2, 3

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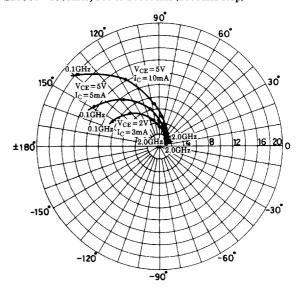
SANYO Electric Co., Ltd. Semiconductor Bussiness Headquaters



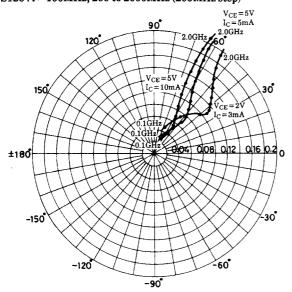
S11e: f=100MHz, 200 to 2000MHz (200MHz step)



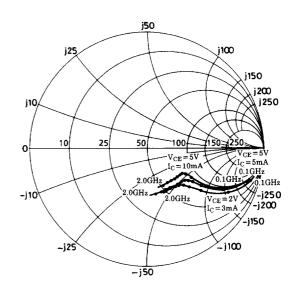
S21e: f=100MHz, 200 to 2000MHz (200MHz step)



 $S12e: f\!=\!100MHz, 200\ to\ 2000MHz\ (200MHz\ step)$ 



S22e: f = 100MHz, 200 to 2000MHz (200MHz step)



# 2SA1963

## **S Parameters** (Common Emitter)

 $V_{CE} = 5V, I_{C} = 5mA, Z_{O} = 50\Omega$ 

Freq (MHz)	S <sub>11</sub>	∠S <sub>11</sub>	S <sub>21</sub>	∠S <sub>21</sub>	S <sub>12</sub>	∠S <sub>12</sub>	S <sub>22</sub>	∠S <sub>22</sub>
100	0.711	-47.7	12.330	149.2	0.033	68.0	0.893	-18.2
200	0.628	-83.9	9.680	127.8	0.052	55.1	0.740	-28.5
400	0.542	-126.7	6.113	104.1	0.069	47.5	0.559	-34.7
600	0.513	-150.7	4.337	90.6	0.080	48.5	0.479	-36.5
800	0.502	-166.1	3.375	80.7	0.091	52.0	0.442	-38.4
1000	0.504	-177.9	2.772	72.7	0.104	55.0	0.424	-41.5
1200	0.506	172.3	2.378	65.5	0.119	57.6	0.416	-45.2
1400	0.509	163.8	2.069	58.5	0.136	59.6	0.409	-49.6
1600	0.516	155.3	1.825	52.1	0.153	61.1	0.403	-55.0
1800	0.527	147.7	1.645	46.4	0.173	61.9	0.403	-60.5
2000	0.541	140.6	1.515	41.3	0.193	62.2	0.406	-66.5

 $V_{CE}$ =5V,  $I_{C}$ =10mA,  $Z_{O}$ =50 $\Omega$ 

Freq (MHz)	S <sub>11</sub>	∠S <sub>11</sub>	S <sub>21</sub>	∠S <sub>21</sub>	S <sub>12</sub>	∠S <sub>12</sub>	S <sub>22</sub>	∠S <sub>22</sub>
100	0.547	-70.6	17.652	139.1	0.027	64.1	0.801	-24.4
200	0.501	-112.1	12.156	117.0	0.040	55.5	0.610	-32.8
400	0.479	-148.5	6.937	97.2	0.056	55.7	0.457	-34.5
600	0.473	-166.7	4.783	85.8	0.071	60.0	0.398	-34.6
800	0.473	-178.8	3.677	77.6	0.088	63.2	0.374	-36.5
1000	0.478	172.1	3.005	70.5	0.107	65.0	0.366	-39.7
1200	0.486	163.7	2.570	63.7	0.126	65.6	0.358	-43.8
1400	0.492	156.4	2.228	57.3	0.147	65.8	0.353	-48.5
1600	0.502	149.2	1.967	51.4	0.166	65.5	0.349	-54.0
1800	0.514	142.4	1.765	45.9	0.188	64.6	0.348	-59.9
2000	0.526	135.6	1.626	42.1	0.209	63.6	0.351	-66.1

 $V_{CE} = 2V, I_C = 3mA, Z_O = 50\Omega$ 

Freq (MHz)	S <sub>11</sub>	∠S <sub>11</sub>	S <sub>21</sub>	∠S <sub>21</sub>	S <sub>12</sub>	∠S <sub>12</sub>	S <sub>22</sub>	∠S <sub>22</sub>
100	0.788	-42.7	8.469	152.2	0.045	68.4	0.913	-17.6
200	0.714	-77.5	6.984	131.1	0.074	53.9	0.780	-29.2
400	0.626	-120.3	4.613	106.0	0.099	40.2	0.586	-38.9
600	0.587	-145.9	3.338	90.6	0.108	36.9	0.491	-42.9
800	0.577	-162.3	2.612	79.5	0.114	38.0	0.443	-46.0
1000	0.574	-174.9	2.173	70.6	0.122	40.9	0.422	-50.2
1200	0.577	174.5	1.872	62.2	0.131	44.2	0.410	-54.7
1400	0.578	165.4	1.637	54.5	0.142	47.9	0.400	-59.8
1600	0.587	157.0	1.447	47.5	0.155	51.1	0.398	-65.9
1800	0.598	149.0	1.303	41.6	0.173	53.7	0.398	-72.0
2000	0.608	141.3	1.203	36.3	0.194	55.6	0.403	-78.8

#### 2SA1963

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